

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Docket No: TI-29600.1

Serial No:

10/719,198

Conf. No:

2992

Examiner:

Shrinivas H. Rao

Gregory E. Howard, et al.

Art Unit:

2814

Filed:

11/21/2003

For:

METHOD FOR CONSTRUCTING A METAL OXIDE SEMICONDUCTOR FIELD EFFECT

TRANSISTOR

EXTENSION OF TIME

Commissioner For Patents P.O. Box 1450 Alexandria, VA 22313-1450 MAILING CERTIFICATE UNDER 37 C.F.R. §1.8(a)

I hereby certify that the above correspondence is being deposited with the U.S. Postal Service with sufficient postage as First Class Mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450 on //-/7-04 .

Dear Sir:

Pursuant to 37 CFR 1.136(a), Applicants respectfully petition the Commissioner for an extension of the shortened statutory period for response in the above identified Application.

The fee for this extension is indicated below:

One Month (\$110) _X_

Three Months (\$980)

Two Months (\$430)

Four Months (\$1,530)

Any further necessary extension of time is hereby requested. Charge any and all fees, or credit any overpayment, to the deposit account of Texas Instruments Incorporated, Account No.

20-0668.

11/24/2004 MAHMED1 00000023 200668 10719198

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110.00 DA

Pèter K. McLarty

Attorney for Applicants

Respectfully submitted,

Reg. No. 44,923

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